NSN 5961-00-547-2596

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-547-2596 **Inclosure Material:** Glass **Overall Length:** Between 0.230 inches and 0.300 inches **Terminal Length:** 1.000 inches **Overall Diameter:** Between 0.085 inches and 0.140 inches **Function For Which Designed:** Voltage variable capacitor **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 15.0 reverse voltage, instantaneous **Current Rating Per Characteristic:** 5.00 nanoamperes zero-gate-voltage source current any acceptable **Capacitance Rating In Picofarads:** Between 71.0 and 75.0 **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli

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